IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: PRITCHARD et al.

Attorney Docket No.:

Application No.: 10/791,337

03-2051/LSI1P240

Filed: March 1, 2004

Examiner: TRINH, Michael Manh

Group: 2822

Title: SPACER-LESS TRANSISTOR INTEGRATION SCHEMB FOR HIGH-K GATE

Confirmation No.: 2401

DIELECTRICS AND SMALL GATE-TO-GATE SPACES APPLICABLE TO SI, SIGE AND

STRAINED SILICON SCHEMES

Entered WIRCE 3/19/04 CERTIFICATE OF FACSIMILE TRANSMISSION

I hereby certify that this correspondence is being transmitted by facsimile to fax sumber 571-273-8300 to the U.S. Patent and Trademark Office on October 18.

Signed:

AMENDMENT B

Mail Stop AF Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In response to the Final Office Action dated September 11, 2006, please amend the above-identified patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begin on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.

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